



IXTQ200N10T Information

Part Number IXTQ200N10T

Manufacturer IXYS

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

MOSFET N-CH 100V 200A TO-3P **Description**

TO-3P-3, SC-65-3 **Package**

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com For Reference Only

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IXTQ200N10T Specifications

Manufacturer Part Number	IXTQ200N10T
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-3P-3, SC-65-3
Series	TrenchMV?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	200A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4.5V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	152nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	9400pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	550W (Tc)
Rds On (Max) @ Id, Vgs	5.5 mOhm @ 50A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-3P
Package / Case	TO-3P-3, SC-65-3
	Report errors?

IXTQ200N10T Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXTQ200N10T Payment Methods



















IXTQ200N10T Shipping Methods













If you have any question about IXTQ200N10T, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com